Complementary Power Transistors

DPAK For Surface Mount Applications

Designed for general purpose amplifier and low speed switching applications.

Features

- Pb-Free Packages are Available
- Lead Formed for Surface Mount Applications in Plastic Sleeves (No Suffix)
- Straight Lead Version in Plastic Sleeves ("-1" Suffix)
- Lead Formed Version Available in 16 mm Tape and Reel ("T4" Suffix)
- Electrically Similar to MJE2955 and MJE3055
- DC Current Gain Specified to 10 Amperes
- High Current Gain–Bandwidth Product $f_T = 2.0 \text{ MHz}$ (Min) @ $I_C = 500 \text{ mAdc}$
- Epoxy Meets UL 94, V-0 @ 0.125 in.
- ESD Ratings: Human Body Model, 3B > 8000 V
 Machine Model, C > 400 V

MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Collector–Emitter Voltage	V_{CEO}	60	Vdc
Collector-Base Voltage	V_{CB}	70	Vdc
Emitter-Base Voltage	V _{EB}	5	Vdc
Collector Current	I _C	10	Adc
Base Current	I _B	6	Adc
Total Power Dissipation @ T _C = 25°C Derate above 25°C	P _D †	20 0.16	W W/°C
Total Power Dissipation* @ T _A = 25°C Derate above 25°C	P _D	1.75 0.014	W W/°C
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction-to-Case	$R_{\theta JC}$	6.25	°C/W
Thermal Resistance, Junction-to-Ambient*	$R_{\theta JA}$	71.4	°C/W

[†]Safe Area Curves are indicated by Figure 1. Both limits are applicable and must be observed.



ON Semiconductor®

http://onsemi.com

SILICON
POWER TRANSISTORS
10 AMPERES
60 VOLTS
20 WATTS

MARKING DIAGRAMS

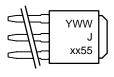


DPAK CASE 369C STYLE 1





DPAK-3 CASE 369D STYLE 1



Y = Year WW = Work Week

xx = 29 or 30

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

^{*}These ratings are applicable when surface mounted on the minimum pad sizes recommended.

ELECTRICAL CHARACTERISTICS ($T_C = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Collector–Emitter Sustaining Voltage (Note 1) $(I_C = 30 \text{ mAdc}, I_B = 0)$	V _{CEO(sus)}	60	-	Vdc
Collector Cutoff Current (V _{CE} = 30 Vdc, I _B = 0)	I _{CEO}	_	50	μAdc
Collector Cutoff Current $(V_{CE} = 70 \text{ Vdc}, V_{EB(off)} = 1.5 \text{ Vdc})$ $(V_{CE} = 70 \text{ Vdc}, V_{EB(off)} = 1.5 \text{ Vdc}, T_{C} = 150^{\circ}\text{C})$	I _{CEX}	- -	0.02 2	mAdc
Collector Cutoff Current $ (V_{CB} = 70 \text{ Vdc}, I_E = 0) $ $ (V_{CB} = 70 \text{ Vdc}, I_E = 0, T_C = 150^{\circ}\text{C}) $	Ісво	<u>-</u>	0.02 2	mAdc
Emitter Cutoff Current (V _{BE} = 5 Vdc, I _C = 0)	I _{EBO}	_	0.5	mAdc
ON CHARACTERISTICS	•			
DC Current Gain (Note 1) ($I_C = 4$ Adc, $V_{CE} = 4$ Vdc) ($I_C = 10$ Adc, $V_{CE} = 4$ Vdc)	h _{FE}	20 5	100 -	-
Collector–Emitter Saturation Voltage (Note 1) ($I_C = 4$ Adc, $I_B = 0.4$ Adc) ($I_C = 10$ Adc, $I_B = 3.3$ Adc)	V _{CE(sat)}	- -	1.1 8	Vdc
Base–Emitter On Voltage (Note 1) (I _C = 4 Adc, V _{CE} = 4 Vdc)	V _{BE(on)}	-	1.8	Vdc
DYNAMIC CHARACTERISTICS				
Current-Gain – Bandwidth Product (I _C = 500 mAdc, V _{CE} = 10 Vdc, f = 500 kHz)	f _T	2	_	MHz

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2%.

ORDERING INFORMATION

Device	Package Type	Package	Shipping [†]
MJD2955	DPAK	369C	75 Units / Rail
MJD2955G	DPAK (Pb–Free)	369C	75 Units / Rail
MJD2955-001	DPAK-3	369D	75 Units / Rail
MJD2955T4	DPAK	369C	2500 Tape & Reel
MJD2955T4G	DPAK (Pb-Free)	369C	2500 Tape & Reel
MJD3055	DPAK	369C	75 Units / Rail
MJD3055T4	DPAK	369C	2500 Tape & Reel
MJD3055T4G	DPAK (Pb-Free)	369C	2500 Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

TYPICAL CHARACTERISTICS

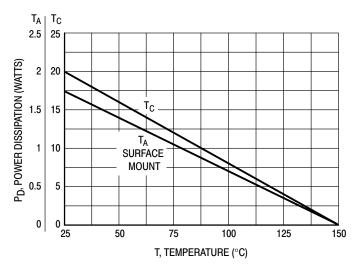


Figure 1. Power Derating

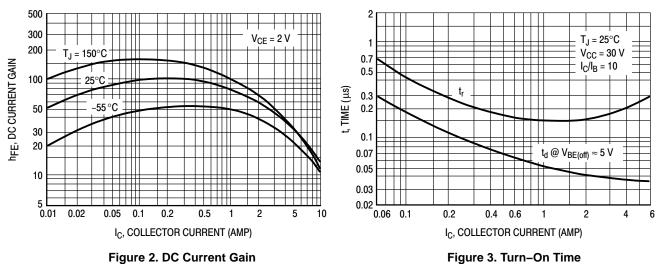


Figure 2. DC Current Gain

1.4

1.2

8.0

0.6

0.4

0.2

0 l

V, VOLTAGE (VOLTS)

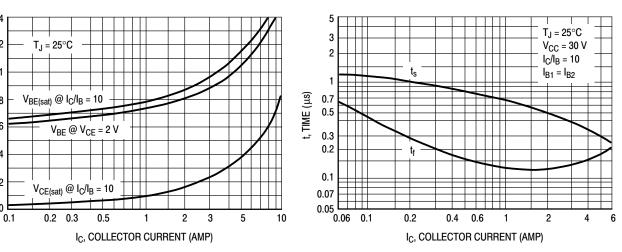


Figure 4. "On" Voltages, MJD3055

Figure 5. Turn-Off Time

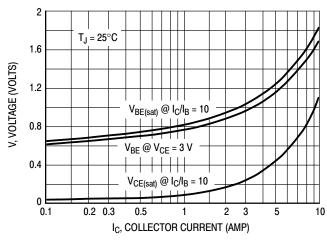
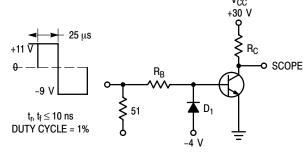


Figure 6. "On" Voltages, MJD2955



 $R_{\mbox{\footnotesize{B}}}$ and $R_{\mbox{\footnotesize{C}}}$ VARIED TO OBTAIN DESIRED CURRENT LEVELS

D₁ MUST BE FAST RECOVERY TYPE, eg: 1N5825 USED ABOVE I_B \approx 100 mA MSD6100 USED BELOW I_B \approx 100 mA

Figure 7. Switching Time Test Circuit

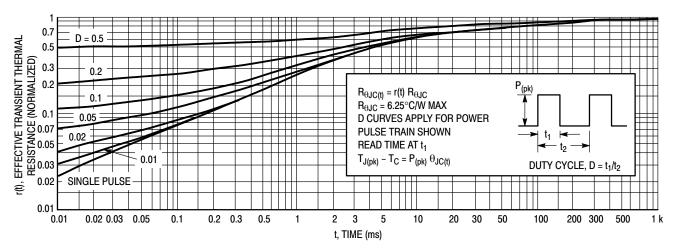


Figure 8. Thermal Response

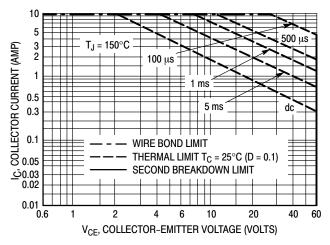


Figure 9. Maximum Forward Bias Safe Operating Area

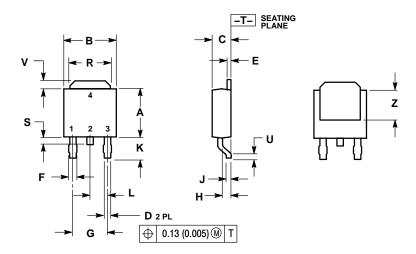
FORWARD BIAS SAFE OPERATING AREA INFORMATION

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 9 is based on $T_{J(pk)} = 150^{\circ} C$; T_{C} is variable depending on conditions. Second breakdown pulse limits are valid for duty cycles to 10% provided $T_{J(pk)} \le 150^{\circ} C$. $T_{J(pk)}$ may be calculated from the data in Figure 8. At high case temperatures, thermal limitations will reduce the power that can be handled to values less than the limitations imposed by second breakdown.

PACKAGE DIMENSIONS

DPAK CASE 369C-01 **ISSUE O**

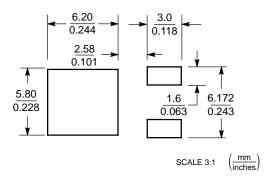


- NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.245	5.97	6.22	
В	0.250	0.265	6.35	6.73	
С	0.086	0.094	2.19	2.38	
D	0.027	0.035	0.69	0.88	
Е	0.018	0.023	0.46	0.58	
F	0.037	0.045	0.94	1.14	
G	0.180	BSC	4.58 BSC		
Н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
K	0.102	0.114	2.60	2.89	
L	0.090	BSC	2.29	BSC	
R	0.180	0.215	4.57	5.45	
S	0.025	0.040	0.63	1.01	
U	0.020		0.51		
٧	0.035	0.050	0.89	1.27	
Z	0.155		3.93		

STYLE 1: PIN 1. BASE 2. COLLECTOR 3. EMITTER 4. COLLECTOR

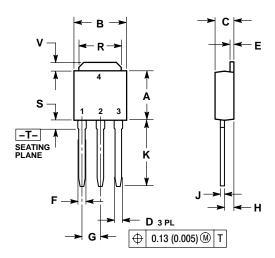
SOLDERING FOOTPRINT*

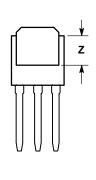


^{*}For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

DPAK-3 CASE 369D-01 ISSUE B





NOTES:

- DIMENSIONING AND TOLERANCING PER
 ANSI V14 FM 1082
- ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INCHES		MILLIN	IETERS	
DIM	MIN	MAX	MIN	MAX	
Α	0.235	0.245	5.97	6.35	
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F	0.037	0.045	0.94	1.14	
G	0.090 BSC		2.29	BSC	
Н	0.034	0.040	0.87	1.01	
J	0.018	0.023	0.46	0.58	
K	0.350	0.380	8.89	9.65	
R	0.180	0.215	4.45	5.45	
S	0.025	0.040	0.63	1.01	
٧	0.035	0.050	0.89	1.27	
Z	0.155		3.93		

STYLE 1:

PIN 1. BASE

2. COLLECTOR

3. EMITTER

. COLLECTOR

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